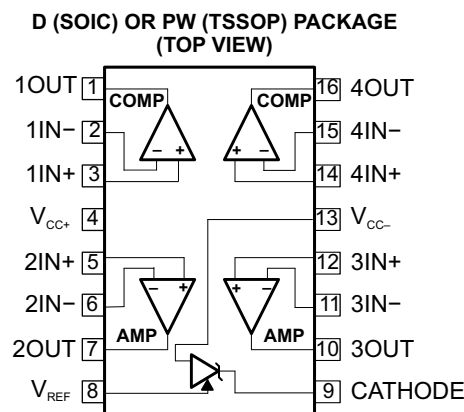


FEATURES

- **OPERATIONAL AMPLIFIERS**
 - Low Supply Current...200 μ A/A
 - Medium Speed...2.1 MHz
 - Low-Level Output Voltage Close to V_{CC} ...0.1 V Typ ($R_L = 10\text{ k}\Omega$)
 - Input Common-Mode Voltage Range Includes Ground
- **COMPARATORS**
 - Low Supply Current...200 μ A/A ($V_{CC} = 5\text{ V}$)
 - Input Common-Mode Voltage Range Includes Ground
 - Low Output Saturation Voltage... Typically 250 mV ($I_{\text{sink}} = 4\text{ mA}$)
- **VOLTAGE REFERENCE**
 - Adjustable Output Voltage... V_{REF} to 36 V
 - Sink Current Capability...1 mA to 100 mA
 - 0.4% (A Grade) and 1% (Standard Grade) Precision
 - Latch-Up Immunity

APPLICATIONS

- Switch-Mode Power Supplies
- Battery Chargers
- Voltage and Current Sensing
- Power-Good, Overvoltage, Undervoltage, Overcurrent Detection
- Window Comparators
- Alarms, Detectors, and Sensors



DESCRIPTION/ORDERING INFORMATION

The TSM102 and TSM102A combine the building blocks of a dual operational amplifier, a dual comparator, and a precision voltage reference, all of which often are used to implement a wide variety of power-management functions, including overcurrent detection, undervoltage/overvoltage detection, power-good detection, window comparators, error amplifiers, etc. Additional applications include alarm and detector/sensor applications.

The TSM102A offers a tight V_{REF} tolerance of 0.4% at 25°C. The TSM102 and TSM102A are characterized for operation from –40°C to 85°C.

ORDERING INFORMATION

| T_A | MAX V_{REF} TOLERANCE (25°C) | PACKAGE ⁽¹⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|--|------------------------|--------------|-----------------------|------------------|
| –40°C to 85°C | A grade: 0.4% precision | SOIC – D | Tube of 75 | TSM102AID | TSM102AI |
| | | | Reel of 2500 | TSM102AIDR | |
| | | TSSOP – PW | Tube of 90 | TSM102AIPW | SN102AI |
| | | | Reel of 2000 | TSM102AIPWR | |
| | Standard grade: 1% precision | SOIC – D | Tube of 75 | TSM102ID | TSM102I |
| | | | Reel of 2500 | TSM102IDR | |
| | | TSSOP – PW | Tube of 90 | TSM102IPW | SN102I |
| | | | Reel of 2000 | TSM102IPWR | |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TSM102, TSM102A

DUAL OPERATIONAL AMPLIFIER, DUAL COMPARATOR, AND VOLTAGE REFERENCE

SLVS602–MARCH 2006

Absolute Maximum Ratings⁽¹⁾

over free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---------------|---|------------|-----|------|
| V_{CC} | Supply voltage | | 36 | V |
| V_{ID} | Input differential voltage | | 36 | V |
| V_I | Input voltage range | –0.3 | 36 | V |
| I_{KA} | Voltage reference cathode current | | 100 | mA |
| θ_{JA} | Package thermal impedance ⁽²⁾⁽³⁾ | D package | | 73 |
| | | PW package | | 108 |
| T_J | Maximum junction temperature | | 150 | °C |
| T_{stg} | Storage temperature range | –65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
- (3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

| | | MIN | MAX | UNIT |
|---------------------|---------------------------------------|-----------|---------------------|------|
| $V_{CC+} - V_{CC-}$ | Supply voltage | 3 | 30 | V |
| V_{ID} | Comparator differential input voltage | | $V_{CC+} - V_{CC-}$ | V |
| V_{KA} | Cathode-to-anode voltage | V_{REF} | 36 | V |
| I_K | Reference cathode current | 1 | 100 | mA |
| T_A | Operating free-air temperature | –40 | 85 | °C |

Total Device Electrical Characteristics

| PARAMETER | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|-----------|--|---|------------|-----|-----|------|
| I_{CC} | Total supply current, excluding reference cathode current | $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0\text{ V}$, No load | 25°C | | 0.8 | 1.5 |
| | | | Full range | | | 2 |
| | | | | | | mA |

Operational Amplifier Electrical Characteristics

$V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, R_1 connected to $V_{CC}/2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|-----------------|--------------------------------|---|------------|-----------|------|-----------------|------------------------------|
| V_{IO} | Input offset voltage | | 25°C | | 1 | 4.5 | mV |
| | | | Full range | | | 6.5 | |
| αV_{IO} | Input offset voltage drift | | 25°C | | 10 | | $\mu\text{V}/^\circ\text{C}$ |
| I_{IO} | Input offset current | | 25°C | | 5 | 20 | nA |
| | | | Full range | | | 40 | |
| I_{IB} | Input bias current | | 25°C | | 20 | 100 | nA |
| | | | Full range | | | 200 | |
| A_{VD} | Large-signal voltage gain | $V_{CC+} = 30\text{ V}$, $R_1 = 10\text{ k}\Omega$, $V_O = 5\text{ V}$ to 25 V | 25°C | 50 | 100 | | V/mV |
| | | | Full range | 25 | | | |
| k_{SVR} | Supply-voltage rejection ratio | $V_{CC+} = 5\text{ V}$ to 30 V | 25°C | 80 | 100 | | dB |
| V_{ICM} | Input common-mode voltage | | 25°C | V_{CC-} | | $V_{CC+} - 1.8$ | V |
| | | | Full range | V_{CC-} | | $V_{CC+} - 2.2$ | |
| $CMRR$ | Common-mode rejection ratio | $V_{CC+} = 30\text{ V}$, $V_{ICM} = 0\text{ V}$ to $V_{CC+} - 1.8\text{ V}$ | 25°C | 70 | 90 | | dB |
| I_{SC} | Short-circuit current | $V_{ID} = \pm 1\text{ V}$, $V_O = 2.5\text{ V}$ | 25°C | Source | 3 | 6 | mA |
| | | | | Sink | 3 | 6 | |
| V_{OH} | High-level output voltage | $V_{CC+} = 30\text{ V}$, $R_L = 10\text{ k}\Omega$ | 25°C | 27 | 28 | | V |
| | | | Full range | 26 | | | |
| V_{OL} | Low-level output voltage | $R_L = 10\text{ k}\Omega$ | 25°C | | 130 | 170 | mV |
| | | | Full range | | | 200 | |
| SR | Slew rate | $V_{CC} = \pm 15\text{ V}$, $C_L = 100\text{ pF}$, $V_I = \pm 10\text{ V}$, $R_L = 10\text{ k}\Omega$ | 25°C | 1.3 | 2 | | V/ μs |
| GBW | Gain bandwidth product | $R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$ | 25°C | 1.4 | 2.1 | | MHz |
| Φ_m | Phase margin | $R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$ | 25°C | | 45 | | ° |
| THD | Total harmonic distortion | | 25°C | | 0.01 | | % |
| V_n | Equivalent input noise voltage | $f = 1\text{ kHz}$ | 25°C | | 19 | | nV/ $\sqrt{\text{Hz}}$ |

TSM102, TSM102A

DUAL OPERATIONAL AMPLIFIER, DUAL COMPARATOR, AND VOLTAGE REFERENCE

SLVS602–MARCH 2006

Comparator Electrical Characteristics

$V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|--|---|------------|-----|-----|-----------------|------|
| V_{IO} Input offset voltage | | 25°C | | | 5 | mV |
| | | Full range | | | 9 | |
| V_{ID} Comparator differential input voltage | | Full range | | | V_{CC+} | V |
| I_{IO} Input offset current | | 25°C | | | 50 | nA |
| | | Full range | | | 150 | |
| I_{IB} Input bias current | | 25°C | | | 250 | nA |
| | | Full range | | | 400 | |
| I_{OH} High-level output current | $V_{ID} = 1\text{ V}$, $V_{CC} = V_O = 30\text{ V}$ | 25°C | | 0.1 | | nA |
| | | Full range | | | 1 | μA |
| V_{OL} Low-level output voltage | $V_{ID} = -1\text{ V}$, $I_{\text{sink}} = 4\text{ mA}$ | 25°C | | 250 | 400 | mV |
| | | Full range | | | 700 | |
| A_{VD} Large-signal voltage gain | $V_{CC+} = 15\text{ V}$, $R_1 = 15\text{ k}\Omega$, $V_O = 1\text{ V to } 11\text{ V}$ | 25°C | | 200 | | V/mV |
| I_{sink} Output sink current | $V_O = 1.5\text{ V}$, $V_{ID} = -1\text{ V}$ | 25°C | 6 | 16 | | mA |
| V_{ICM} Input common-mode voltage range | | 25°C | 0 | | $V_{CC+} - 1.5$ | V |
| | | Full range | 0 | | $V_{CC+} - 2$ | |
| t_{RESP} Response time ⁽¹⁾ | $R_1 = 5.1\text{ k}\Omega$ to V_{CC+} , $V_{\text{REF}} = 1.4\text{ V}$ | 25°C | | 1.3 | | μs |
| $t_{\text{RESP,large}}$ Large-signal response time | $R_1 = 5.1\text{ k}\Omega$ to V_{CC+} , $V_{\text{REF}} = 1.4\text{ V}$, $V_I = \text{TTL}$ | 25°C | | 300 | | ns |

(1) The response-time specification is for 100-mV input step with 5-mV overdrive. For larger overdrive signals, 300 ns can be obtained.

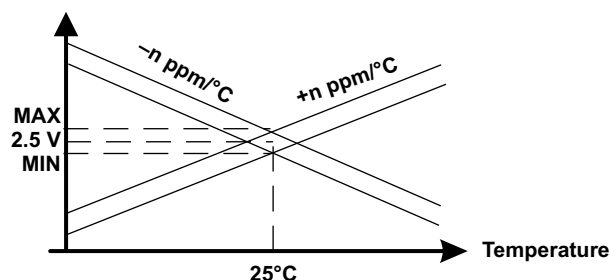
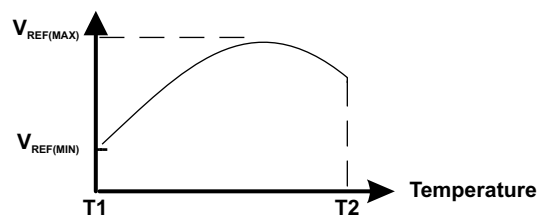
Voltage-Reference Electrical Characteristics

| PARAMETER | | TEST CONDITIONS | T _A | MIN | TYP | MAX | UNIT |
|--------------------------|---|---|----------------|-------|------|-------|--------|
| V _{REF} | Reference voltage ⁽¹⁾ | V _{KA} = V _{REF} , I _K = 10 mA, See Figure 1 | 25°C | 2.475 | 2.5 | 2.525 | V |
| | | | 25°C | 2.49 | 2.5 | 2.51 | |
| ΔV _{REF} | Reference input voltage deviation over temperature range ⁽¹⁾ | V _{KA} = V _{REF} , I _K = 10 mA, See Figure 1 | Full range | | 7 | 30 | mV |
| $\frac{V_{REF}}{T}$ | Average temperature coefficient of reference input voltage ⁽²⁾ | V _{KA} = V _{REF} , I _K = 10 mA | Full range | | ±22 | ±100 | ppm/°C |
| $\frac{V_{REF}}{V_{KA}}$ | Ratio of change in reference voltage to change in cathode voltage | V _{KA} = 3 V to 36 V, I _K = 10 mA, See Figure 2 | 25°C | | –1.1 | –2 | mV/V |
| I _{REF} | Reference input current | I _K = 10 mA, R ₁ = 10 kΩ, R ₂ = ∞, See Figure 2 | 25°C | | 1.5 | 2.5 | μA |
| | | | Full range | | | 3 | |
| ΔI _{REF} | Reference input current deviation over temperature range | I _K = 10 mA, R ₁ = 10 kΩ, R ₂ = ∞, See Figure 2 | Full range | | 0.5 | 1 | μA |
| I _{min} | Minimum cathode current for regulation | V _{KA} = V _{REF} , See Figure 1 | 25°C | | 0.5 | 1 | mA |
| I _{K,OFF} | Off-state cathode current | See Figure 3 | 25°C | | 180 | 500 | nA |

(1) ΔV_{REF} is defined as the difference between the maximum and minimum values obtained over the full temperature range.

$$\Delta V_{REF} = V_{REF(MAX)} - V_{REF(MIN)}$$

(2) The temperature coefficient is defined as the slopes (positive and negative) of the voltage vs temperature limits within which the reference voltage is specified.



PARAMETER MEASUREMENT INFORMATION

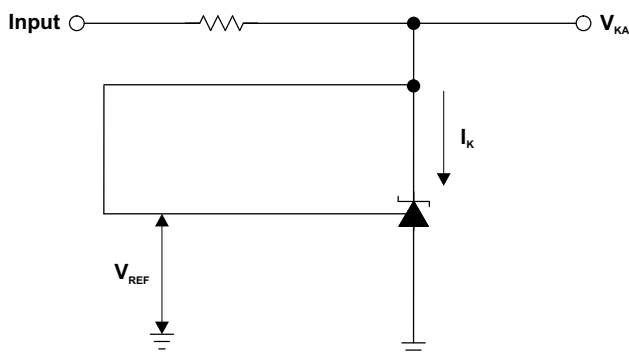


Figure 1. Test Circuit for $V_{KA} = V_{REF}$

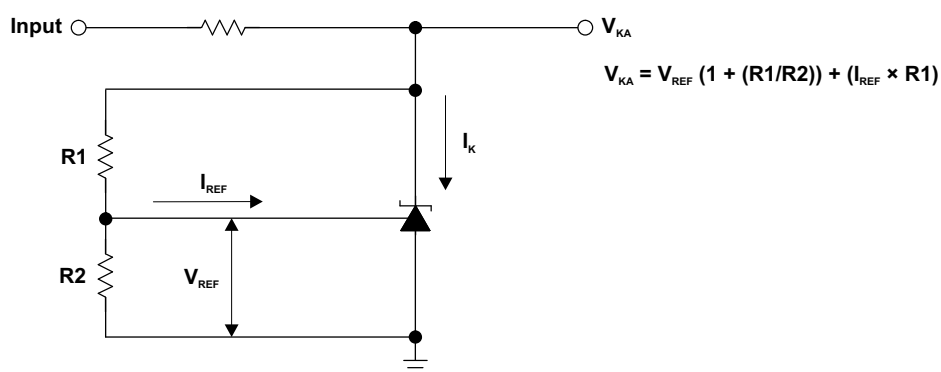


Figure 2. Test Circuit for $V_{KA} > V_{REF}$

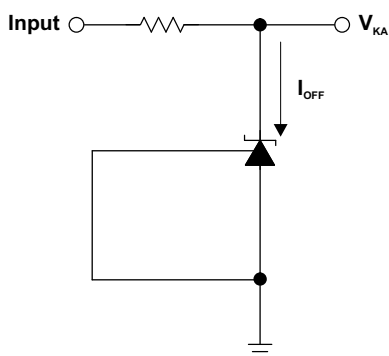


Figure 3. Test Circuit for I_{OFF}

TYPICAL CHARACTERISTICS

AMPLIFIER TOTAL HARMONIC DISTORTION
VS
FREQUENCY

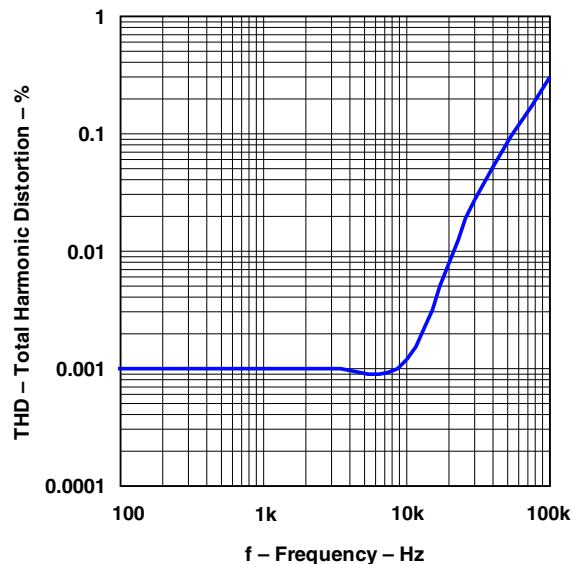


Figure 4.

AMPLIFIER NOISE VOLTAGE
VS
FREQUENCY

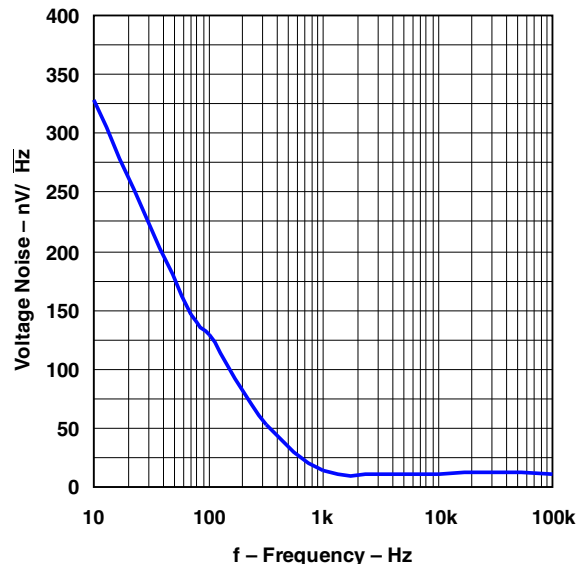


Figure 5.

GAIN AND PHASE
VS
FREQUENCY

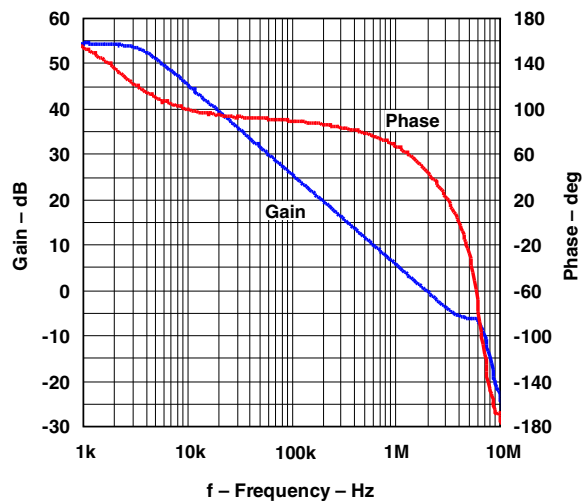


Figure 6.

V_{REF} STABILITY
VS
CAPACITANCE

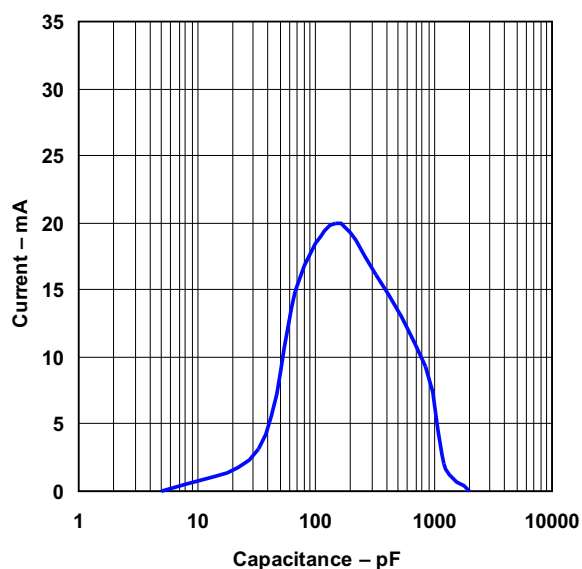


Figure 7.

TYPICAL CHARACTERISTICS (continued)

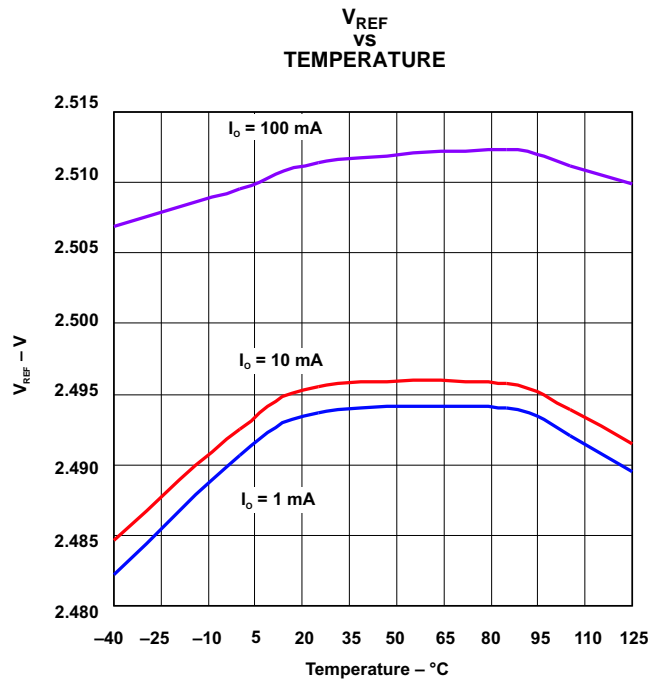


Figure 8.

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|-----------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TSM102AIDR | Active | Production | SOIC (D) 16 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102AI |
| TSM102AIDR.A | Active | Production | SOIC (D) 16 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102AI |
| TSM102AIPW | Active | Production | TSSOP (PW) 16 | 90 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102AI |
| TSM102AIPW.A | Active | Production | TSSOP (PW) 16 | 90 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102AI |
| TSM102AIPWR | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102AI |
| TSM102AIPWR.A | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102AI |
| TSM102ID | Active | Production | SOIC (D) 16 | 40 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102I |
| TSM102ID.A | Active | Production | SOIC (D) 16 | 40 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102I |
| TSM102IDR | Active | Production | SOIC (D) 16 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102I |
| TSM102IDR.A | Active | Production | SOIC (D) 16 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TSM102I |
| TSM102IPWR | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102I |
| TSM102IPWR.A | Active | Production | TSSOP (PW) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | SN102I |

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TSM102AIDR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| TSM102AIPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TSM102IDR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| TSM102IPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TSM102AIDR | SOIC | D | 16 | 2500 | 353.0 | 353.0 | 32.0 |
| TSM102AIPWR | TSSOP | PW | 16 | 2000 | 353.0 | 353.0 | 32.0 |
| TSM102IDR | SOIC | D | 16 | 2500 | 353.0 | 353.0 | 32.0 |
| TSM102IPWR | TSSOP | PW | 16 | 2000 | 353.0 | 353.0 | 32.0 |

TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|--------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TSM102AIPW | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| TSM102AIPW.A | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| TSM102ID | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| TSM102ID.A | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.



4220204/B 12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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